



# **General Multilayer Ceramic Capacitors**



MLCC is an electronic part that temporarily stores an electrical charge and the most prevalent type of capacitor today. New technologies have enabled the MLCC manufacturers to follow the trend dictated by smaller and smaller electronic devices such as Cellular telephones, Computers, DSC, DVC

## **General Features**

- Miniature Size
- Wide Capacitance and Voltage Range
- Tape & Reel for Surface Mount Assembly
- Low ESR

## **Applications**

- General Electronic Circuit

## Part Numbering

CL	<u>10</u>	<u>B</u>	<u> 104</u>	K	<u>B</u>	<u>8</u>	N	N	N	<u>C</u>
0	2	3	4	6	6	Ū	8	9	1	<b>(</b>

- Samsung Multilayer Ceramic Capacitor
- 2 Size(mm)
- 3 Capacitance Temperature Characteristic
- 4 Nominal Capacitance
- **6** Capacitance Tolerance
- 6 Rated Voltage

- Thickness Option
- 8 Product & Plating Method
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- Reserved For Future Use
- Packaging Type

# **1** Samsung Multilayer Ceramic Capacitor

# 2 SIZE(mm)

Code	EIA CODE	Size(mm)
03	0201	0.6 × 0.3
05	0402	1.0 × 0.5
10	0603	1.6 × 0.8
21	0805	2.0 × 1.25
31	1206	3.2 × 1.6
32	1210	3.2 × 2.5
43	1812	4.5 × 3.2
55	2220	5.7 × 5.0





## **3** CAPACITANCE TEMPERATURE CHARACTERISTIC

Code		Temperatu	Temperature Range		
С		COG	C△	0 ± 30 (ppm/ °C)	
Р		P2H	P△	-150±60	
R		R2H	R△	-220±60	
S	Class	S2H	S△	-330±60	-55 ~ +125℃
Т		T2H	T△	-470±60	
U		U2J	U△	-750±60	
L		S2L	S△	+350 ~ -1000	
Α		X5R	X5R	±15%	-55 ~ +85℃
В	Class II	X7R	X7R	±15%	-55 ~ +125℃
X	Ciass II	X6S	X6S	±22%	-55 ~ +105℃
F		Y5V	Y5V	+22 ~ -82%	-30 ~ +85℃

### **\*** Temperature Characteristic

Temperature Characteristics	Below 2.0pF	2.2 ~ 3.9pF	Above 4.0pF	Above 10pF
СФ	COG	COG	COG	C0G
Р∆	-	P2J	P2H	P2H
R∆	-	R2J	R2H	R2H
SΔ	-	S2J	S2H	S2H
ТΔ	-	T2J	T2H	T2H
UΔ	-	U2J	U2J	U2J

 $J:\pm 120$ PPM/°C,  $H:\pm 60$ PPM/°C,  $G:\pm 30$ PPM/°C

## **4** NOMINAL CAPACITANCE

Nominal capacitance is identified by 3 digits.

The first and second digits identify the first and second significant figures of the capacitance.

The third digit identifies the multiplier. 'R' identifies a decimal point.

# Example

Code	Nominal Capacitance
1R5	1.5pF
103	10,000pF, 10nF, 0.01 μ F
104	100,000pF, 100nF, 0.1 μ F





# **O CAPACITANCE TOLERANCE**

Code	Tolerance	Nominal Capacitance
Α	±0.05pF	
В	±0.1pF	
С	±0.25pF	Less than 10pF (Including 10pF)
D	± 0.5pF	(morading Topi )
F	±1pF	
F	±1%	
G	±2%	
J	±5%	More than 10pF
K	±10%	More than 10pF
М	±20%	
Z	+80, -20%	

# **6** RATED VOLTAGE

Code	Rated Voltage	Code	Rated Voltage
R	4.0V	D	200 V
Q	6.3V	E	250V
Р	10V	G	500 V
О	16V	Н	630 V
Α	25V	I	1,000V
L	35V	J	2,000V
В	50V	К	3,000V
С	100V		





# THICKNESS OPTION

Size	Code	Thickness(T)	Size	Code	Thickness(T)
0201(0603)	3	0.30±0.03		F	1.25±0.20
0402(1005)	5	0.50±0.05		н	1.6±0.20
0603(1608)	8	0.80±0.10	1812(4532)	I	2.0±0.20
	Α	0.65±0.10		J	2.5±0.20
	С	0.85±0.10		L	3.2±0.30
0805(2012)	F	1.25±0.10		F	1.25±0.20
	Q	1.25±0.15		н	1.6±0.20
	Y	1.25±0.20	2220(5750)	ı	2.0±0.20
	С	0.85±0.15		J	2.5±0.20
1206(3216)	F	1.25±0.15		L	3.2±0.30
	Н	1.6±0.20			
	F	1.25±0.20			
1210(3225)	н	1.6±0.20			
	ı	2.0±0.20			
	J	2.5±0.20			
	V	2.5±0.30			

# PRODUCT & PLATING METHOD

Code	Electrode	Termination	Plating Type
Α	Pd	Ag	Sn_100%
N	Ni	Cu	Sn_100%
G	Cu	Cu	Sn_100%

## SAMSUNG CONTROL CODE

Code	Description of the code	Code	Description of the code
Α	Array (2-element)	N	Normal
В	Array (4-element)	Р	Automotive
С	High - Q	L	LICC





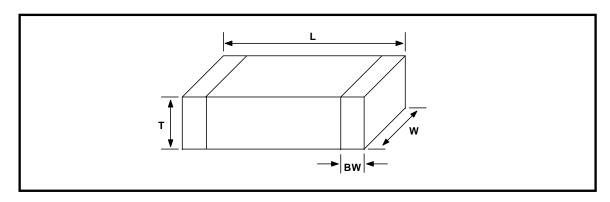
## **T** RESERVED FOR FUTURE USE

Code	Description of the code
N	Reserved for future use

# **1** PACKAGING TYPE

Code	Packaging Type	Code	Packaging Type
В	Bulk	F	Embossing 13" (10,000EA)
Р	Bulk Case	L	Paper 13" (15,000EA)
С	Paper 7"	0	Paper 10"
D	Paper 13" (10,000EA)	S	Embossing 10"
Е	Embossing 7"		

# APPEARANCE AND DIMENSION



CODE	EIA CODE	DIMENSION ( mm )							
CODE	EIA CODE	L	w	T (MAX)	BW				
03	0201	0.6 ± 0.03	0.3 ± 0.03	0.33	0.15 ± 0.05				
05	0402	1.0 ± 0.05	0.5 ± 0.05	0.55	0.2 +0.15/-0.1				
10	0603	1.6 ± 0.1	0.8 ± 0.1	0.9	0.3 ± 0.2				
21	0805	2.0 ± 0.1	1.25 ± 0.1	1.35	0.5 +0.2/-0.3				
24	4000	3.2 ± 0.15	1.6 ± 0.15	1.40	0.5 +0.2/-0.3				
31	1206	$3.2 \pm 0.2$	1.6 ± 0.2	1.8	0.5 +0.3/-0.3				
20	1210	3.2 ± 0.3	2.5 ± 0.2	2.7	0.6 ± 0.3				
32	1210	$3.2 \pm 0.4$	2.5 ± 0.3	2.8	0.6 ± 0.3				
43	1812	4.5 ± 0.4	3.2 ± 0.3	3.5	0.8 ± 0.3				
55	2220	5.7 ± 0.4	5.0 ± 0.4	3.5	1.0 ± 0.3				





NO	ITE	М	PER	FORMANCE	TEST	CONDITION							
1	Appea	rance	No Abnormal Exterior	Appearance	Through Microscope(x10	)							
2	Insula Resist		10,000№ or 500№-иF  Rated Voltage is below 10,000№ or 100№-иF	w 16V ;	Apply the Rated Voltage For 60 ~ 120 Sec.								
3	Withsta	•	No Dielectric Breakdov Mechanical Breakdowr		Class I: 300% of the Rated Voltage for 1-5 sec. Class II: 250% of the Rated Voltage for 1-5 sec. is applied with less than $50\text{mA}$ current								
					Capacitance	Frequency	Voltage						
		Class ī	Within the specifie	ed tolerance	≤ 1,000 pF	1 Mb ±1 0%	0.5 5 1/200						
	Capacita	1			>1,000 pF	1 kHz ±1 0%	0.5 ~ 5 Vrms						
4	nce				Capacitance	Frequency	Voltage						
		Class	Within the specifi	ied tolerance	≤ 10 μF	1 kHz ±1 0%	1.0±0.2Vrms						
		П			>10 µF	120 Hz ± 20%	0.5±0.1Vrms						
			Capacitance ≥ 30pF :	Q ≥ 1.000	Capacitance	Frequency	Voltage						
5	5 Q Class		· ·	: Q ≥ 400 +20C	≤ 1,000 pF	1™z ±1 0%							
		I	( C	: Capacitance )	>1,000 pF	1kHz ±10%	0.5 ~ 5 Vrms						
			1. Characteristic : A()	X5R), B(X7R), X(X6S)	Capacitance	Frequency	Voltage						
			Rated Voltage	Spec	≤ 10 μF	1 kHz ±1 0%	1.0±0.2Vrms						
			≥ 25V	0.025 max	>10 µF	120 Hz ± 20%	0.5±0.1Vrms						
			16V	0.035 max									
			10V	0.05 max									
			6.3V	0.05 max/ 0.10max*1	*1. 0201 C≥0.022uF, 0	402 C≥0.22uF,	0603 C≥2.2uF,						
									2. Characteristic : F(	Y5V)	D805 C≥4.7uF, 1206 1812 C≥47uF, 2220 All Low Profile Capa 1 *2 0603 C≥0.47uF, 08	C≥100uF, citors (P.16).	) C≥22uF,
6	Tan $\delta$	Class	Rated Voltage	Spec	2 0603 C≥0.47uF, 06								
		П	50V	0.05 max, 0.07max*2	All 0805, 1206 size		F						
			35V	0.07 max	*4 1210 C>6.8uF								
			25V	0.05 max/ 0.07 max*³/ 0.09max*⁴	*5 0402 C≥0.22uF								
			16V 0.09 max/ 0.125max*5		*6 All 1812 size								
			10V	0.125 max/ 0.16max*6									
			6.3V	0.16max									





NO	ITEM PERFORMANCE						TEST CONDITION			
NO	ITE	<b>M</b>		PERFOR	MANCE		TEST CONDITION			
					· '	shall be measured by the steps				
			Characte	rictice	Temp. Coefficient	shown in the	following table.			
			Cilalacte	HISTICS	(PPM/℃)	Step	Temp.(℃)			
			C00	3	0 ± 30	1	25 ± 2			
		Class	PH	ı	-150 ± 60	2	Min. operating temp. $\pm$ 2			
		I	RH	1	-220 ± 60	3	25 ± 2			
		_	SH	ı	-330 ± 60	4	Max. operating temp $\pm$ 2			
			TH		-470 ± 60	5	25 ± 2			
			UL		-750 ± 120	(1) Class I	20 - 2			
			SL		+350 ~ -1000	` ′	Coefficient shall be calculated from			
	Temperature					the formula a				
7	Characteristics of Capacitance					Temp, Coefficie	$nt = \frac{C2 - C1}{C1 \times \triangle T} \times 10^6 \text{ [ppm/°C]}$			
						' '	ance at step 3			
		Class II	Characte	eristics	Capacitance Change with No Bias	C2: Capacita  △T: 60 °C (=8				
			A(X5 B(X7		± 15%	(2) CLASS II				
		_	X(Xe	SS)	± 22%	Capacitance (	Change shall be calculated from the			
			F(Y5	5V)	+22% ~ -82%	formula as be	elow.			
				•		$\triangle C = \frac{C2 - C2}{C4}$	C1 × 100(%)			
							ance at step 3			
							ance at step 2 or 4			
							* Pressure for 10±1 sec.			
						' ' '	201 case size.			
8	Adhesive	•			ing Shall Occur On The					
	of Termi	ination	Terminal E	lectrode.			500g.f			
							<b>-</b>			
		A = = = · · · · ·	NI=			Bending limit	; 1mm			
		Apperance	No mecha	anical dam	nage shall occur.	Test speed ;	1.0mm/SEC.			
			Charac	teristics	Capacitance Change	Keep the test	board at the limit point in 5 sec.,			
						Then measure	e capacitance.			
					Within $\pm$ 5% or $\pm$ 0.					
			Clas	ss I	5 pF whichever is		20			
					larger		R=230			
9	Bending			A 0/2=1:		50				
	Strength	Capacitance		A(X5R)/	NAPUL : + 10 551	_ /*!				
		Сараскансе		B(X7R)/	Within ± 12.5%		<del>_</del> <del>_</del> <del>_</del>			
				X(X6S)		<b>│</b>	Donding the te			
			Class II			45±1	Bending limit			
				F(Y5V)	Within ± 30%					
				'(13v)	VIIIIII = 30 /0					





NO	IT	EM		PERF	ORMANCE	TEST CONDITION				
			More Than	1 75% of th	e terminal surface is to	Solder	Sn-3Ag-0.5	Cu 63Sn-37Pb		
			be soldere	d newly, So	metal part does not	Solder	e 000	00		
			come out	come out or dissolve			245±5℃	235±5℃		
10	Solde	erability					R	MA Type		
			<b></b> // // <del>-</del> -			Dip Tim	e 3±0.3 sec	5±0.5 sec.		
						Pre-heatir	ng at 80~120	°C for 10~30 sec.		
		Apperance	No mecha	anical dam	age shall occur.	Solder Te	mperature : 270	±5℃		
			1	teristics	Capacitance Change	Dip Time	: 10±1 sec.			
					Within ±2.5% or	Each term	ination shall be	fully immersed and		
			Clas	s I	±0.25pF whichever is	preheated	as below:			
					larger					
		Capacitance		A(X5R)/		STEP	TEMP.(℃)	TIME(SEC.)		
				B(X7R)	Within ±7.5%	1	80~100	60		
			Class II	X(X6S)	Within ±15%	2	150~180	60		
	Resistance to			F	Within ±20%	Leave the	capacitor in an	bient condition for		
11	Soldering heat		Capacitar	nce ≥ 30pF	: Q≥ 1000	Leave the capacitor in ambient condition for specified time* before measurement				
		Q		<b>&lt;30</b> pF	: Q≥ 400+20×C	* 24 ± 2	hours (Class I	)		
		(Class I)			(C: Capacitance)	24 ± 2	hours (Class ${\mathbb I}$	)		
		Tan δ	İ							
		(Class Ⅱ)	Within the	e specified	initial value					
		Insulation								
		Resistance	Within the	e specified	initial value					
		Withstanding	Within the specified initial value							
		Voltage	vvidilir die	Specified	initial value					
		Appearance	No mecha	anical dam	age shall occur.					
					<del>-</del>					
			Charact	eristics	Capacitance Change	The capacitor shall be subjected to a				
				_	Within ±2.5% or			total amplitude of		
			Clas	s l	±0.25 pF whichever is		ŭ	y from 10Hz to 55H		
		Capacitance		10/50/	larger		to 10Hz In 1 m	-		
				A(X5R)/ B(X7R)	Within ±5%					
12	Vibration		Class	X(X6S)	Within 1109/	Repeat th	is for 2hours ea	ch in 3 mutually		
	Test		111	F(Y5V)	Within ±10% Within ±20%	perpendicu	ular directions			
		Q		F(15V)	VVIIIIII ±20%					
		(Class I)	Within the	e specified	initial value					
		Tan ∂								
		(Class II)	Within the	e specified	initial value					
						-				
		Insulation Resistance	Within the	Within the specified initial value						
		Resistance								





NO	ITE	М		PERFOI	RMANCE	TEST CONDITION		
		Appearance	No mechanic	al damage shal	l occur.	Temperature : 40±2 ℃		
				cteristics	Capacitance Change	Relative humidity : 90~95 %RH		
			Onara	otoriotico		Duration time : 500 +12/-0 hr.		
			Cla	ss I	Within ±5.0% or ±0.5pF whichever is larger	200 112 0 111.		
				l	willchever is larger	Leave the capacitor in ambient		
		Capacitance		A(X5R)/		condition for specified time* before		
			Class	B(X7R)/	Within ±12.5%	measurement.		
					П	X(X6S)		CLASS I : 24±2 Hr.
				F(Y5V)	Within ±30%	CLASSII : 24±2 Hr.		
		Q	Capacitance	≥ <b>30</b> pF : <b>Q</b> ≥ :	350			
	Humidity	CLASSI			≥ 275 + 2.5×C			
13	(Steady			<u> </u>	200 + 10×C (C: Capacitance)			
	State)		1. Characteri	stic: A(X5R),	2. Characteristic : F(Y5V)			
				B(X7R)				
			0.05max (16\	•	0.075max (25V and over)			
		Tan $\delta$	0.075max (10	OV)	0.1max (16V, C<1.0μF)			
		CLASS II	0.075max		$0.125 \text{max} (16 \text{V}, \text{ C} \ge 1.0 \mu\text{F})$			
			(6.3V excep	t Table 1)	0.15max (10V)			
			0.125max* 0.195max (6.3V)		0.195max (6.3V)			
			(refer to Tab	le 1)				
		Insulation		= a)(0 E   1   1				
		Resistance	1,000 MM2 or	50MΩ.μF whichev	er is smaller.			
		Appearance	No mechanic	al damage shal	l occur.	Applied Voltage : rated voltage		
		Capacitance	Chara	cteristics	Capacitance Change	Temperature: 40±2 °C		
					Within ±5.0% or ±0.5pF	- Humidity::90~95%RH Duration Time:500 +12/-0 Hr.		
			Cla	ss I	whichever is larger	Charge/Discharge Current : 50mA max.		
			A(X5R)/		Within ±12.5%			
				B(X7R)/	Within ±12.5%	Perform the initial measurement according to		
				X(X6S)	Within ±30%	Note1.		
			Class II	( /	Within ±30%	-		
					Within 130%	Perform the final measurement according to		
				F(Y5V)	Within ±30%	Note2.		
					20070			
	Moisture			> 00 F 0> 0	00			
14	Resistance	Q (Class I.)	'	≥ 30pF : Q≥ 2	0 + 10/3×C (C: Capacitance)			
		(Class I)	Capacitance	<30 pr : Q≥ 10	0 + 10/3×C (C: Capacitance)			
			1. Characteri	stic: A(X5R),	2. Characteristic : F(Y5V)			
				B(X7R)				
			0.05max (16\	/ and over)	0.075max (25V and over)			
			0.075max (10	OV)	0.1max (16V, C<1.0μF)			
		Tan $\delta$	0.075max		0.125max(16V, C≥ 1.0 $\mu$ F)			
		(Class II)	(6.3V excep	t Table 1)	0.15max (10V)			
		` ′	0.125max*		0.195max (6.3V)			
			(refer to Tal	ble 1)				
			X(X6S) 0.11r	nax (6.3V and b	pelow)			
		Insulation	500 MΩ or 25	5MΩ-μF whichever	is smaller.			
		Resistance						





NO	ITE	М		PERI	FORMANCE		TEST CONDIT	ION		
		Appearance	No mechanio	cal damage	shall occur.	1	oltage: 200%* of the	•		
			Charact	eristics	Capacitance Change		re : max. operating t ime : 1000 +48/-0 Hi			
					Within ±3% or ±0.3pF,	Charge/Discharge Current : 50m/ max.				
			Class	s I	Whichever is larger	* votov to				
		Capacitance		A(X5R)/ B(X7R)	Within ±12.5%	voltage	* refer to table(3): 150%/100% of the rated voltage			
			Class II	X(X6S)	Within ±25%	Perform th	e initial measurement	according to		
					Within ±30%	Note1 for	Class II			
				F(Y5V)	Within ±30%					
		_	Capacitance	≥30pF : C	Q ≥ 350	Porform th	e final measurement	according to		
		Q (Obs. T)	10≤ Capaci	tance <30 p	$F : Q \ge 275 + 2.5 \times C$	Note2.	e iliai measurement	according to		
	I EL	(Class I)	Capacitance	< 10pF :Q	≥ 200 +10×C (C: Capacitance)					
45	High		Characteristic : A(X5R), 2. Characteristic : F							
15	Temperature Resistance			B(X7R)	)					
	Resistance		0.05max		0.075max					
			(16V and o	•	(25V and over)					
			0.075max (1)	0V)	0.1max(16V, C<1.0μF)					
		Tan ∂	0.075max		0.125max(16V, C≥1.0 <i>μ</i> F)					
		(Class Ⅱ)	(6.3V excep	ot Table 1)	0.15max (10V)					
			0.125max*		0.195max (6.3V)					
			(refer to Ta	ble 1)						
			X(X6S) 0.11	max (6.3V a	nd below)					
		Insulation Resistance	1,000 MΩ or	50MΩ-μF whic	chever is smaller.					
		Appearance	No mechanio	cal damage	shall occur.	Capacito	shall be subjected	d to 5 cycles.		
			Charact	eristics	Capacitance Change	Condition	for 1 cycle :			
			Olasa	. т	Within ±2.5% or ±0.25pF	Step	Temp.(℃)	Time(min.)		
			Class	<b>i</b> 1	Whichever is larger	_	Min. operating	30		
		Capacitance		A(X5R)/	\A(\frac{1}{2} - \frac{7}{2} \) \( \frac{1}{2} - \frac{1}{2} \) \( \frac{1}{2} - \frac{1}{2} \) \( \frac{1}{2} - \frac{1}{2} - \frac{1}{2} \) \( \frac{1}{2} - \frac{1}{2}	1	temp.+0/-3			
			Class	B(X7R)/	Within ±7.5%	2	25	2~3		
16	Temperature		П	X(X6S)	Within ±15%	3	Max. operating	30		
	Cycle			F(Y5V)	Within ±20%		temp.+3/-0			
		Q	Mithin the	nooified initi	al value	4	25	2~3		
		(Class I)	Within the sp	pediled initia	ıı value	Leave the	e capacitor in amb	ient condition		
		Tan δ	VA Calcination		1	for specif	ied time* before m	neasurement		
		(Class II)	Within the sp	pearied initia	ai value	* 24 ± 2	* 24 ± 2 hours (Class I)			
		Insulation	VA Calcination		al control	24 ± 2 hours (Class II)				
		Resistance	Within the sp	pecified initia	ai value					





		Rece	ommended Sold	ering Method		
		Size	Temperature		Cond	lition
		inch (mm)	Characteristic	Capacitance	Flow	Reflow
		0201 (0603)	-	-	-	0
		0402 (1005)				
			Class I	-	0	0
		0603 (1608)	Class II	$C < 1\mu F$	0	0
			Class II	$C \geq 1\mu$ F	-	0
	Recommended	0805 (2012)	Class I	-	0	0
18	Soldering Method		Class II	C < 4.7μF	0	0
	By Size & Capacitance		Class II	$C \geq 4.7 \mu F$	•	0
	by the a tapathanes		Array	-	-	0
			Class I	-	0	0
		1206 (3216)	Class II	C < 10μF	0	0
		1200 (3210)	Class II	$C \geq 10 \mu F$	-	0
			Array	-	-	0
		1210 (3225)				0
		1808 (4520)				0
		1812 (4532)	_	-	-	0
		2220 (5750)				0

Note1. Initial Measurement For Class  $\ensuremath{\mathbb{I}}$ 

Perform the heat treatment at  $150^{\circ}\text{C}+0/-10^{\circ}\text{C}$  for 1 hour. Then Leave the capacitor in ambient condition for  $48\pm4$  hours before measurement. Then perform the measurement.

#### Note2. Latter Measurement

### 1. CLASS I

Leave the capacitor in ambient condition for 24±2 hours before measurement

Then perform the measurement.

#### 2. Class ${\mathbb I}$

Perform the heat treatment at  $150\,^{\circ}\text{C} + 0/-10\,^{\circ}\text{C}$  for 1 hour. Then Leave the capacitor in ambient condition for  $48\pm4$  hours before measurement. Then perform the measurement.

\*Table1.

Tan ∂
Tan δ  Class Ⅱ  A(X5R),  B(X7R)

\*Table2.

High Tem	perature Resistance test
⊿C (Y5V)	± 30%
	0402 C ≥ 0.47 <i>μ</i> F
	$0603 \ C \ \geq 2.2 \mu F$
Class∏	0805 C ≥ $4.7\mu$ F
F(Y5V)	1206 C ≥ 10.0 <i>μ</i> F
1 (130)	1210 C ≥ 22.0 $\mu$ F
	1812 C ≥ 47.0 $\mu$ F
	2220 C ≥ 100.0 $\mu$ F

\*Table3.

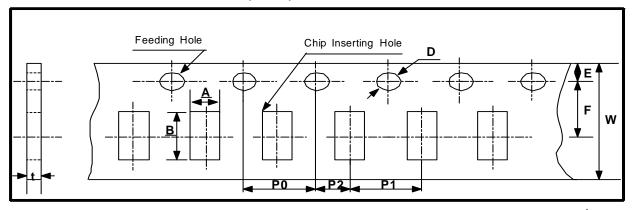
	High Temperature Resi	stance test
Applied Voltage	100% of the rated voltage	150% of the rated voltage
Class II A(X5R), B(X7R), X(X6S), F(Y5V)	0201 C $\geq$ 0.1 $\mu$ F 0402 C $\geq$ 1.0 $\mu$ F 0603 C $\geq$ 4.7 $\mu$ F 0805 C $\geq$ 22.0 $\mu$ F 1206 C $\geq$ 47.0 $\mu$ F 1210 C $\geq$ 100.0 $\mu$ F All Low Profile Capacitors (P.16).	$\begin{array}{llll} 0201 & C & \geq 0.022\mu F \\ 0402 & C & \geq 0.47\mu F \\ 0603 & C & \geq 2.2\mu F \\ 0805 & C & \geq 4.7\mu F \\ 1206 & C & \geq 10.0\mu F \\ 1210 & C & \geq 22.0\mu F \\ 1812 & C & \geq 47.0\mu F \\ 2220 & C & \geq 100.0\mu F \end{array}$





# **PACKAGING**

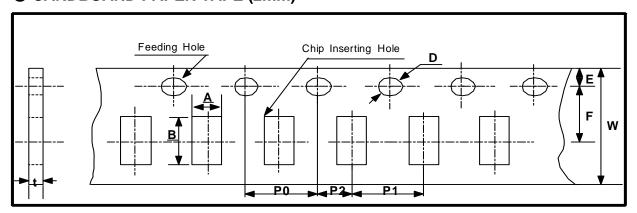
# ● CARDBOARD PAPER TAPE (4mm)



unit : mm

	mbol ype	Α	В	w	F	E	P1	P2	P0	D	t
D i m	0603 (1608)	1.1 ±0.2	1.9 ±0.2								
e n s	0805 (2012)	1.6 ±0.2	2.4 ±0.2	8.0 ±0.3	3.5 ±0.05	1.75 ±0.1	4.0 ±0.1	2.0 ±0.05	4.0 ±0.1	Ф1.5 +0.1/-0	1.1 Below
i o n	1206 (3216)	2.0 ±0.2	3.6 ±0.2								

# ● CARDBOARD PAPER TAPE (2mm)



unit: mm

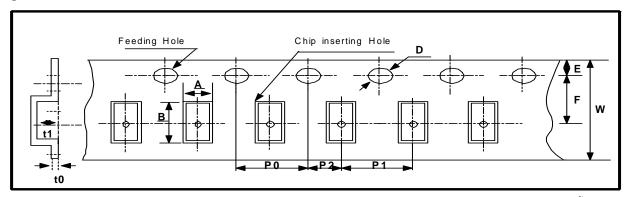
	Symbol Type	Α	В	w	F	E	P1	P2	P0	D	t
D i m e	0201 (0603)	0.38 ±0.03	0.68 ±0.03	8.0	3.5	1.75	2.0	2.0	4.0	Ф1.5	0.37 ±0.03
n s i o n	0402 (1005)	0.62 ±0.04	1.12 ±0.04	±0.3	±0.05	±0.1	±0.05	±0.05	±0.1	+0.1/-0.03	0.6 ±0.05





# **PACKAGING**

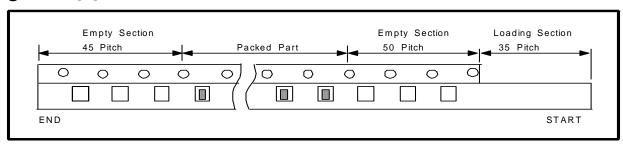
## **● EMBOSSED PLASTIC TAPE**



unit: mm

	m bol ype	Α	В	w	F	E	P1	P2	P 0	D	t1	t0
	0805 (2012)	1.45 ±0.2	2.3 ±0.2									
P	1206 (3216)	1.9 ±0.2	3.5 ±0.2	8.0 ±0.3	3.5 ±0.05		4.0 ±0.1				2.5 max	
m e	1210 (3225)	2.9 ±0.2	3.7 ±0.2			1.75		2.0	4.0	Ф1.5 +0.1/-0		0.6
n s i	1808 (4520)	2.3 ±0.2	4.9 ±0.2			±0.1		±0.05	±0.1	+0.1/-0		Below
o n	1812 (4532)	3.6 ±0.2	4.9 ±0.2	12.0 ±0.3	5.60 ±0.05		8.0 ±0.1				3.8 max	
	2220 (5750)	5.5 ±0.2	6.2 ±0.2									

## **TAPING SIZE**



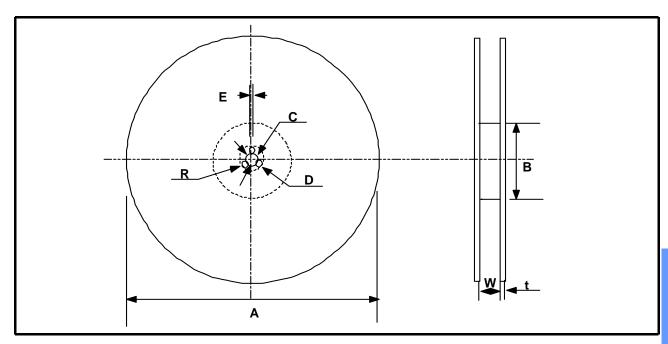
Туре	Symbol	Size	Cardboard Paper Tape	Symbol	Size	Embossed Plastic Tape
		0201(0603)	10,000		All Size ≤3216 1210(3225),1808(4520) (t≤1.6mm)	2,000
7" Reel	С	0402(1005)	10,000	E	1210(3225)(t≥2.0mm)	1,000
		OTHERS	4,000		1808(4520)(t≥2.0mm)	1,000
10" Reel	0	-	10,000	-	-	-
	D	0402(1005)	50,000		All Size ≤3216 1210(3225),1808(4520) (t<1.6mm)	10,000
		OTHERS	10,000		$1210(3225)(1.6 \le t < 2.0 \text{ m m})$ $1206(3216)(1.6 \le t)$	8,000
13" Reel		0603(1608)	10,000 or 15,000	F	$1210(3225),1808(4520) $ $(t \ge 2.0 \text{mm})$	4,000
	L	0805(2012) (t≤0.85mm)	15,000 or 10,000(Option)		1812(4532)(t≤2.0mm)	4,000
		1206(3216) (t≤0.85mm)	10,000		1812(4532)(t>2.0mm) 5750(2220)	2,000





# **PACKAGING**

# • REEL DIMENSION



unit: mm

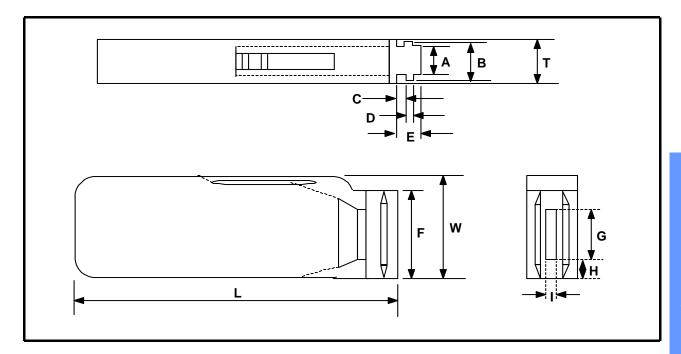
Symbol	Α	В	С	D	E	W	t	R
7" Reel	ф180+0/ -3	ф60+1/ -3	442   0.2	25   2.5	20105	0.14.5	1.2±0.2	4.0
13" Reel	ф330±2.0	φ80+1/ -3	φ13±0.3	25±0.5	2.0±0.5	9±1.5	2.2±0.2	1.0





## BULK CASE PACKAGING

- Bulk case packaging can reduce the stock space and transportation costs.
- The bulk feeding system can increase the productivity.
- It can eliminate the components loss.



unit: mm

Symbol	Α	В	T	С	D	E
Dimension	6.8±0.1	8.8±0.1	12±0.1	1.5+0.1/-0	2+0/-0.1	3.0+0.2/-0

Symbol	F	W	G	Н	L	I
Dimension	31.5+0.2/-0	36+0/-0.2	19±0.35	7±0.35	110±0.7	5±0.35

### QUANTITY OF BULK CASE PACKAGING

unit : pcs

Ci=o	0402(4005)	06.03/46.09\	0805(	2012)
Size	0402(1005)	0603(1608)	T=0.65mm	T=0.85mm
Quantity	50,000	10,000 or 15,000	10,000	5,000 or 10,000

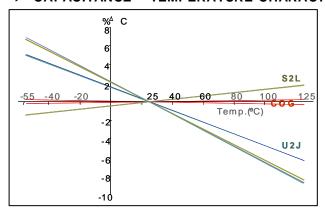


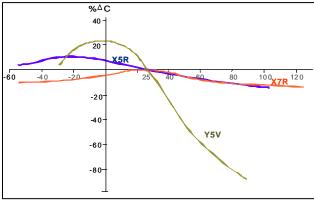


# **APPLICATION MANUAL**

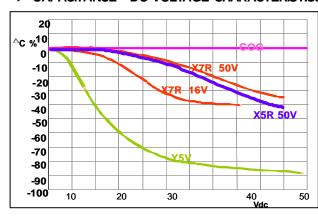
### ELECTRICAL CHARACTERISTICS

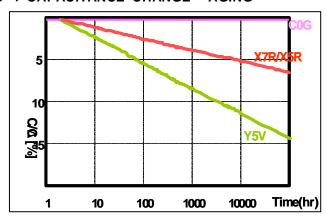
### ► CAPACITANCE - TEMPERATURE CHARACTERISTICS



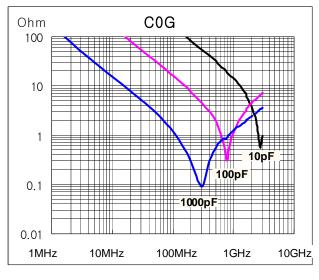


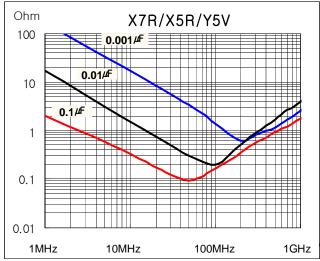
#### ► CAPACITANCE - DC VOLTAGE CHARACTERISTICS ► CAPACITANCE CHANGE - AGING





#### ► IMPEDANCE - FREQUENCY CHARACTERISTICS









### STORAGE CONDITION

## ▶ Storage Environment

The electrical characteristics of MLCCs were degraded by the environment of high temperature or humidity. Therefore, the MLCCs shall be stored in the ambient temperature and the relative humidity of less than 40°C and 70%, respectively.

Guaranteed storage period is within 6 months from the outgoing date of delivery.

#### Corrosive Gases

Since the solderability of the end termination in MLCC was degraded by a chemical atmosphere such as chlorine, acid or sulfide gases, MLCCs must be avoid from these gases.

### ▶ Temperature Fluctuations

Since dew condensation may occur by the differences in temperature when the MLCCs are taken out of storage, it is important to maintain the temperature-controlled environment.

#### DESIGN OF LAND PATTERN

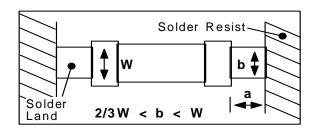
When designing printed circuit boards, the shape and size of the lands must allow for the proper amount of solder on the capacitor.

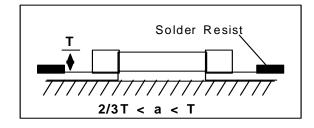
The amount of solder at the end terminations has a direct effect on the crack.

The crack in MLCC will be easily occurred by the tensile stress which was due to too much amount of solder. In contrast, if too little solder is applied, the termination strength will be insufficiently.

Use the following illustrations as guidelines for proper land design.

Recommendation of Land Shape and Size.









#### ADHESIVES

When flow soldering the MLCCs, apply the adhesive in accordance with the following conditions.

### ► Requirements for Adhesives

They must have enough adhesion, so that, the chips will not fall off or move during the handling of the circuit board.

They must maintain their adhesive strength when exposed to soldering temperature.

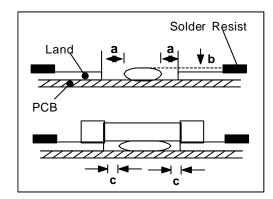
They should not spread or run when applied to the circuit board.

They should harden quickly. They should not corrode the circuit board or chip material.

They should be a good insulator. They should be non-toxic, and not produce harmful gases, nor be harmful when touched.

### ▶ Application Method

It is important to use the proper amount of adhesive. Too little and much adhesive will cause poor adhesion and overflow into the land, respectively.



		unit : mm
Туре	21	31
а	0.2 min	0.2 min
b	70~100 µm	70~100 µm
С	> 0	> 0

### Adhesive hardening Characteristics

To prevent oxidation of the terminations, the adhesive must harden at 160 ℃ or less, within 2 minutes or less.

#### MOUNTING

### Mounting Head Pressure

Excessive pressure will cause crack to MLCCs. The pressure of nozzle will be 300g maximum during mounting.

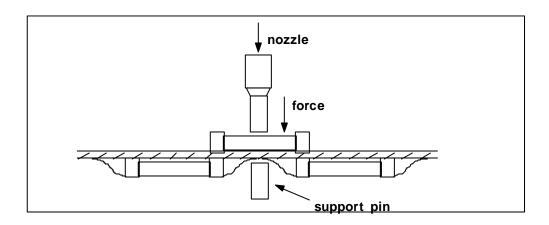




## ▶ Bending Stress

When double-sided circuit boards are used, MLCCs first are mounted and soldered onto one side of the board. When the MLCCs are mounted onto the other side,

it is important to support the board as shown in the illustration. If the circuit board is not supported, the crack occur to the ready-installed MLCCs by the bending stress.



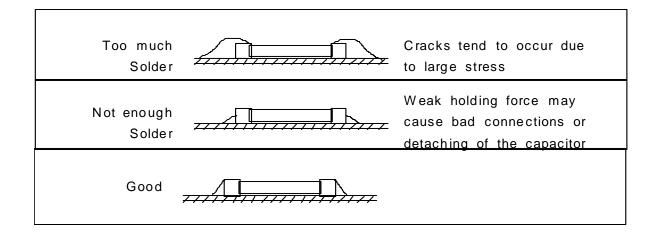
### Manual Soldering

Manual soldering can pose a great risk of creating thermal cracks in chip capacitors.

The hot soldering iron tip comes into direct contact with the end terminations, and operator's carelessness may cause the tip of the soldering iron to come into direct contact with the ceramic body of the capacitor.

Therefore the soldering iron must be handled carefully, and close attention must be paid to the selection of the soldering iron tip and to temperature control of the tip.

### Amount of Solder







## ▶ Cooling

Natural cooling using air is recommended. If the chips are dipped into solvent for cleaning, the temperature difference( $\triangle T$ ) must be less than 100  $^{\circ}$ C

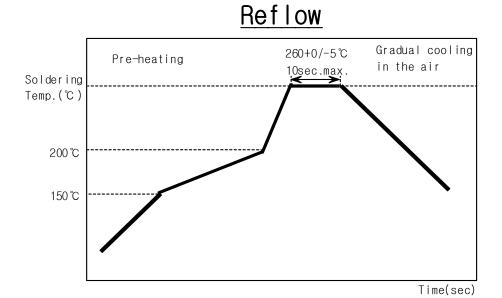
### Cleaning

If rosin flux is used, cleaning usually is unnecessary. When strongly activated flux is used, chlorine in the flux may dissolve into some types of cleaning fluids, thereby affecting the chip capacitors. This means that the cleaning fluid must be carefully selected, and should always be new.

## ▶ Notes for Separating Multiple, Shared PC Boards.

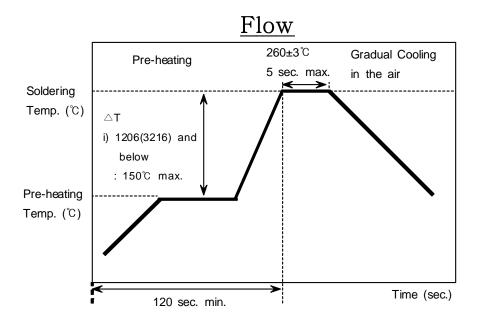
A multi-PC board is separated into many individual circuit boards after soldering has been completed. If the board is bent or distorted at the time of separation, cracks may occur in the chip capacitors. Carefully choose a separation method that minimizes the bending often circuit board.

## ▶ Recommended Soldering Profile









# Soldering Iron

Variation of Temp.	Soldering	Pre-heating	Soldering	Cooling
	Temp (℃)	Time (Sec)	Time(Sec)	Time(Sec)
△T≤130	300±10℃max	≥ 60	≤ 4	-

Condition of Iron facilities				
Wattage Tip Diameter		Soldering Time		
20W Max	3mm Max	4 Sec Max		

<sup>\*</sup> Caution - Iron Tip Should Not Contact With Ceramic Body Directly.